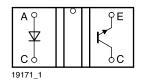


Vishay Semiconductors

Transmissive Optical Sensor with Phototransistor Output





DESCRIPTION

The TCST1030 is a transmissive sensor that include an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light.

FEATURES

• Package type: leaded

• Detector type: phototransistor

• Dimensions (L x W x H in mm): 8.3 x 4.7 x 8.15

Gap (in mm): 3.1Aperture: none

• Typical output current under test: I_C = 2.4 mA

Daylight blocking filter

• Emitter wavelength: 950 nm

• Lead (Pb)-free soldering released

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





ROHS

APPLICATIONS

- · Optical switch
- Shaft encoder
- Detection of opaque material such as paper
- Detection of magnetic tapes

PRODUCT SUMMARY					
PART NUMBER	GAP WIDTH (mm)	APERTURE WIDTH (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (1) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED	
TCST1030	3.1	-	2.4	Yes	

Note

⁽¹⁾ Conditions like in table basic characteristics/coupler

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
TCST1030	Tube	MOQ: 5200 pcs, 65 pcs/tube	3.4 mm lead length		

Note

⁽¹⁾ MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
COUPLER					
Total power dissipation	T _{amb} ≤ 25 °C	P _{tot}	250	mW	
Ambient temperature range		T _{amb}	- 25 to + 85	°C	
Storage temperature range		T _{stg}	- 25 to + 100	°C	
Soldering temperature	1.6 mm from case, t ≤ 10 s	T _{sd}	260	°C	
INPUT (EMITTER)			·		
Reverse voltage		V _R	6	V	
Forward current		I _F	60	mA	
Forward surge current	t _p ≤ 10 μs	I _{FSM}	3	Α	
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW	
Junction temperature		T _i	100	°C	

Document Number: 83763 Rev. 1.8, 20-Sep-10 For technical questions, contact: sensorstechsupport@vishay.com

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
OUTPUT (DETECTOR)	OUTPUT (DETECTOR)						
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ic	100	mA			
Power dissipation	T _{amb} ≤ 25 °C	P _V	150	mW			
Junction temperature		Tj	100	°C			

ABSOLUTE MAXIMUM RATINGS

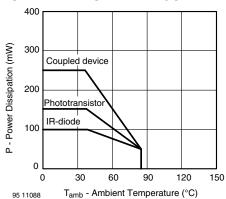


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER						
Collector current	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}$	I _C	1.2	2.4		mA
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}			0.8	V
INPUT (EMITTER)						
Forward voltage	I _F = 60 mA	V _F		1.25	1.5	V
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j		50		pF
OUTPUT (DETECTOR)						
Collector emitter voltage	I _C = 1 mA	V_{CEO}	70			V
Emitter collector voltage	I _E = 10 μA	V _{ECO}	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I _{CEO}		10	100	nA
SWITCHING CHARACTERISTICS						
Turn-on time	$I_C = 1$ mA, $V_{CE} = 5$ V, $R_L = 100 \Omega$ (see figure 2)	t _{on}		15		μs
Turn-off time	$I_C = 1$ mA, $V_{CE} = 5$ V, $R_L = 100 \Omega$ (see figure 2)	t _{off}		10		μs



Transmissive Optical Sensor with Phototransistor Output

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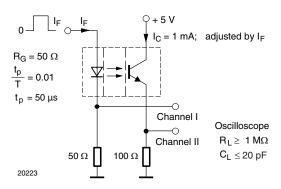


Fig. 2 - Test Circuit for ton and toff

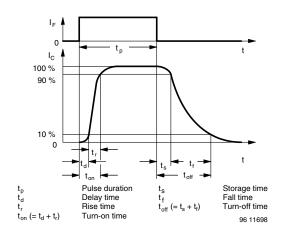


Fig. 3 - Switching Times

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

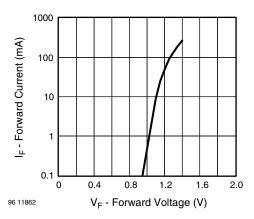


Fig. 4 - Forward Current vs. Forward Voltage

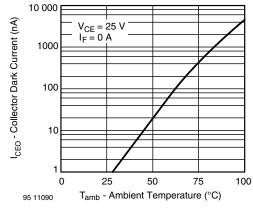


Fig. 6 - Collector Dark Current vs. Ambient Temperature

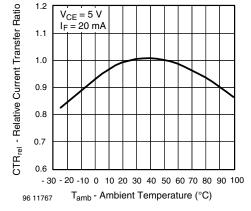


Fig. 5 - Relative Current Transfer Ratio vs. Ambient Temperature

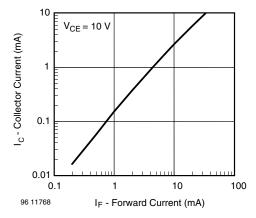


Fig. 7 - Collector Current vs. Forward Current

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Transmissive Optical Sensor with Phototransistor Output



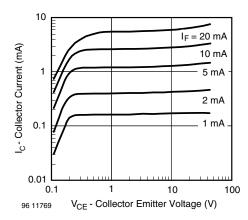


Fig. 8 - Collector Current vs. Collector Emitter Voltage

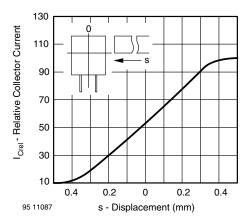


Fig. 11 - Relative Collector Current vs. Displacement

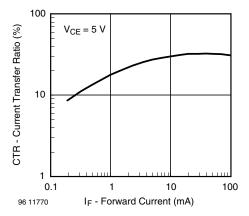


Fig. 9 - Current Transfer Ratio vs. Forward Current

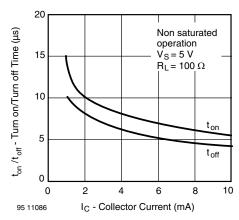


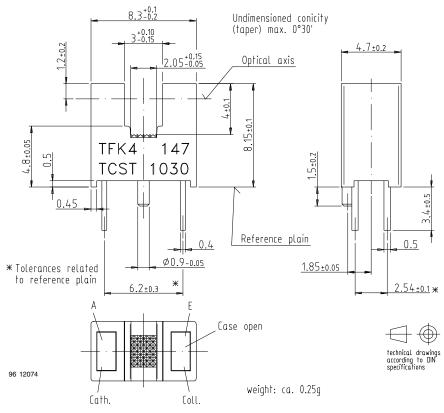
Fig. 10 - Turn-on/Turn-off Time vs. Collector Current



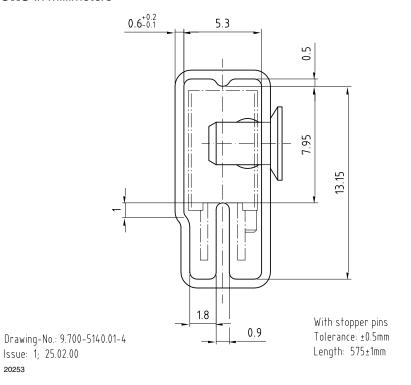
Transmissive Optical Sensor with Phototransistor Output

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PACKAGE DIMENSIONS in millimeters



TUBE DIMENSIONS in millimeters



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